SN74AHCT1G126-Q1 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT SCLS505B – JUNE 2003 – REVISED FEBRUARY 2008

- Qualified for Automotive Applications
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0), 1000-V Charged-Device Model
- Operating Range of 3 V to 5.5 V
- Max t_{pd} of 6 ns at 5 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±8-mA Output Drive at 5 V
- Inputs Are TTL-Voltage Compatible

description/ordering information

The SN74AHCT1G126 is a single bus buffer gate/line driver with 3-state output. The output is disabled when the output-enable (OE) input is low. When OE is high, true data is passed from the A input to the Y output.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

ORDERING INFORMATION[†]

T _A		PACKAGI	E‡	ORDERABLE PART NUMBER	TOP-SIDE MARKING [§]
-40°C to 125	S∘C	SOT (SC-70) – DCK	Reel of 3000	CAHCT1G126QDCKRQ1	BN_

[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.

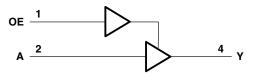
[‡] Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.

§ The actual top-side marking has one additional character that designates the assembly/test site.

F		TADLE				
IN	PUTS	OUTPUT				
OE	Α	Y				
Н	Н	Н				
н	L	L				
L	Х	Z				

FUNCTION TABLE

logic diagram (positive logic)



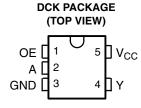


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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 3)

		MIN	MAX	UNIT
V _{CC}	Supply voltage	3	5.5	V
	$V_{\rm CC} = 3.0 \text{ V}$	1.4		
V _{IH}	High-level input voltage V _{CC} = 4.5 V to 5.5 V	2		V
V	Low-level input voltage		0.53	v
V _{IL}	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$			v
VI	Input voltage	0	5.5	V
Vo	Output voltage	0	V_{CC}	V
I _{OH}	High-level output current		-8	mA
I _{OL}	Low-level output current		8	mA
$\Delta t / \Delta v$	Input transition rise or fall rate		20	ns/V
T _A	Operating free-air temperature	-40	125	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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			Τ,	λ = 25°C					
PARAMETER	TEST CONDITIONS	v _{cc}	MIN	TYP MAX		MIN	MAX	UNIT	
		3 V	2.9	3		2.9		v	
	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4			
V_{OH}	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.34		v	
	I _{OH} = -8 mA	4.5 V	3.94			3.66			
	I _{OL} = 50 μA	3 V and 4.5 V			0.1		0.1		
V _{OL}	$I_{OL} = 4 \text{ mA}$	3 V			0.36		0.52	V	
	I _{OL} = 8 mA	4.5 V			0.36		0.52		
l _l	$V_I = 5.5 \text{ V or GND}$	0 V to 5.5 V			±0.1		±1	μA	
I _{OZ}	$V_{O} = V_{CC}$ or GND	5.5 V			±0.25		±2.5	μA	
I _{CC}	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$, OE high or low	3 V and 5.5 V			1		10	μA	
ΔI_{CC}^{\dagger}	One input at 3.4 V, Other input at V _{CC} or GND	5.5 V			1.35		1.5	mA	
Ci	$V_I = V_{CC}$ or GND	5 V		4	10		10	pF	
Co	$V_{O} = V_{CC}$ or GND	5 V		10				pF	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

[†] This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.

switching characteristics over recommended operating	free-air temperature range,
V_{CC} = 3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)	

DADAMETED	FROM	то	LOAD	T _A = 25	°C		
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN TYF	MAX	MIN MAX	UNIT
t _{PLH}		Y	0 45 5	5.6	8	12	
t _{PHL}	A	Y	C _L = 15 pF	5.6	8	12	ns
t _{PZH}	AF.	Y	0 45 5	5.4	8	11.5	
t _{PZL}	OE	Y	C _L = 15 pF	5.4	8	11.5	ns
t _{PHZ}	ŌĒ	V	Y C _L = 15 pF 6.5 9	5 9.7	14.5	ns	
t _{PLZ}	UE	T	$C_{L} = 15 \text{ pm}$	6.5	5 9.7	14.5	115
t _{PLH}		Y.	0 50 5	8.1	11.5	16	
t _{PHL}	A	Y	C _L = 50 pF	8.1	11.5	16	ns
t _{PZH}		X	0 50 - 5	7.9) 11.5	15	
t _{PZL}	ŌĒ	Y	C _L = 50 pF	7.9) 11.5	15	ns
t _{PHZ}	ŌĒ	Y	C _L = 50 pF	8	3 13.2	18	-
t _{PLZ}	UE	r	$C_{L} = 50 \text{ pF}$	8	3 13.2	18	ns



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

BADAMETER	FROM	то	LOAD	Τį	λ = 25°C	;			
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	UNIT
t _{PLH}		X	0 45 - 5		3.8	5.5		8.5	
t _{PHL}	A	Y	C _L = 15 pF		3.8	5.5		8.5	ns
t _{PZH}	05	N/	0 15 -5		3.6	5.1		7.5	
t _{PZL}	OE	Y	C _L = 15 pF		3.6	5.1		7.5	ns
t _{PHZ}	OE	Y	C _L = 15 pF		4.8	6.8		10	-
t _{PLZ}	UE	Ť	$C_L = 15 \text{ pr}$		4.8	6.8		10	ns
t _{PLH}		X	0 50 - 5		5.3	7.5		10.5	
t _{PHL}	A	Y	C _L = 50 pF		5.3	7.5		10.5	ns
t _{PZH}	05	N N	0 50 - 5		5.1	7.1		9.5	
t _{PZL}	OE	Y	C _L = 50 pF		5.1	7.1		9.5	ns
t _{PHZ}		Y	C _L = 50 pF		7	8.8		12	ns
t _{PLZ}	OE	Ť	$O_L = 50 \text{ pm}$		7	8.8		12	ns

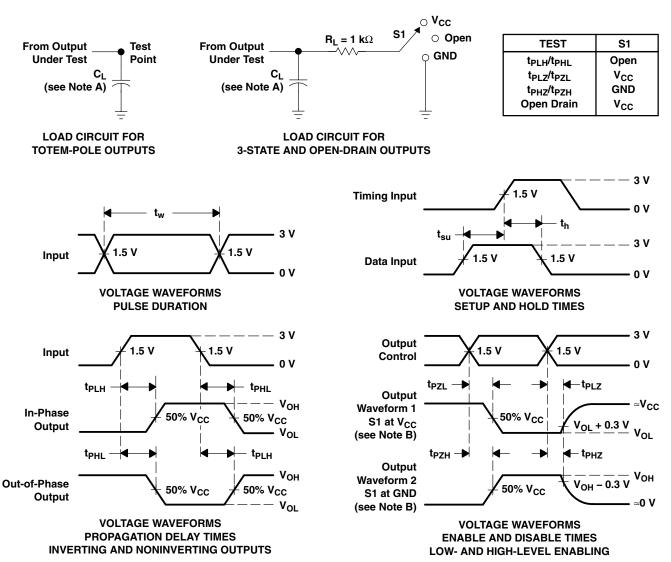
operating characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER	TEST C	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	14	pF



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r \leq 3 ns, t_f \leq 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CAHCT1G126QDCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BNU	Samples
CAHCT1G126QDCKRG4Q	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BNS	Samples
CAHCT1G126QDCKRQ1	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BNS	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

6-Feb-2020

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74AHCT1G126-Q1 :

• Catalog: SN74AHCT1G126

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal				
Device	Package	Package	Pins	SPQ

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CAHCT1G126QDCKRG4	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

3-Aug-2017



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CAHCT1G126QDCKRG4	SC70	DCK	5	3000	203.0	203.0	35.0

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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